



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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CPH3123/CPH3223

Bipolar Transistor (-50V, (-)3A, Low VCE(sat), (PNP)NPN Single CPH3

ON Semiconductor®

http://onsemi.com

Applications

- DC-DC converters, relay drivers, lamp drivers, motor drivers, flash

Features

- Adoption of MBIT processes
- Large current capacity
- Low collector-to-emitter saturation voltage
- High-speed switching
- Ultrasmall package facilitates miniaturization in end products (mounting height : 0.9mm)
- High allowable power dissipation

Specifications () : CPH3123

Absolute Maximum Ratings at Ta=25°C

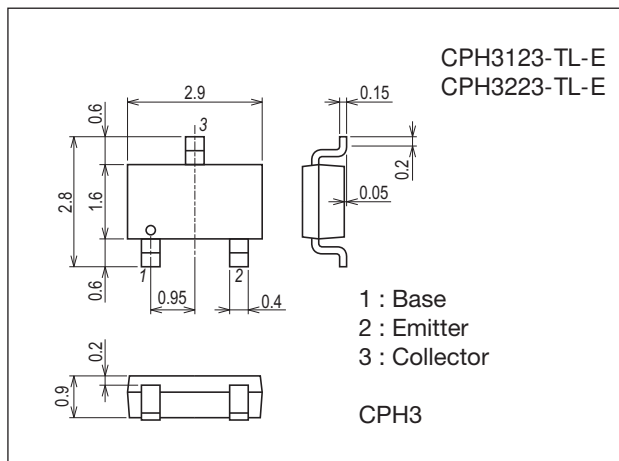
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(-50)100	V
Collector-to-Emitter Voltage	V _{CES}		(-50)100	V
Collector-to-Emitter Voltage	V _{CEO}		(-50)	V
Emitter-to-Base Voltage	V _{EB0}		(-6)	V
Collector Current	I _C		(-3)	A
Collector Current (Pulse)	I _{CP}		(-6)	A
Base Current	I _B		(-600)	mA
Collector Dissipation	P _C	When mounted on ceramic substrate (600mm ² ×0.8mm)	0.9	W
Junction Temperature	T _j		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

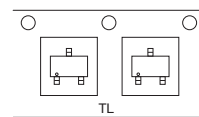
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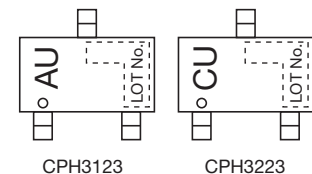
Product & Package Information

- Package : CPH3
- JEITA, JEDEC : SC-59, TO-236, SOT-23
- Minimum Packing Quantity : 3,000 pcs./reel

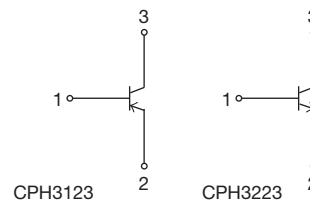
Packing Type: TL



Marking



Electrical Connection

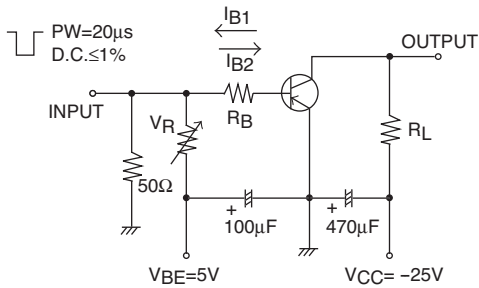


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Electrical Characteristics at Ta=25°C

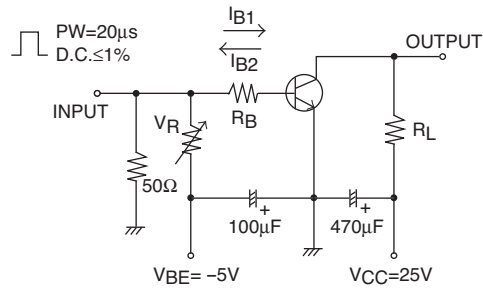
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = (-)40V, I_E = 0A$			(-)1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = (-)4V, I_C = 0A$			(-)1	μA
DC Current Gain	h_{FE}	$V_{CE} = (-)2V, I_C = (-)100mA$	200		560	
Gain-Bandwidth Product	f_T	$V_{CE} = (-)10V, I_C = (-)500mA$		(390)380		MHz
Output Capacitance	C_{ob}	$V_{CB} = (-)10V, f = 1MHz$		(24)13		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)1}$	$I_C = (-)1A, I_B = (-)50mA$		(-115)90	(-230)130	mV
	$V_{CE(sat)2}$	$I_C = (-)2A, I_B = (-)100mA$		(-240)160	(-650)240	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = (-)2A, I_B = (-)100mA$		(-)0.88	(-)1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = (-)10\mu A, I_E = 0A$	(-50)100			V
Collector-to-Base Breakdown Voltage	$V_{(BR)CES}$	$I_C = (-)100\mu A, R_{BE} = 0\Omega$	(-50)100			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = (-)1mA, R_{BE} = \infty$	(-)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = (-)10\mu A, I_C = 0A$	(-)6			V
Turn-On Time	t_{on}	See specified Test Circuit.		(30)35		ns
Storage Time	t_{stg}			(230)300		ns
Fall Time	t_f			(18)25		ns

Switching Time Test Circuit



$$I_C = -10I_{B1} = 10I_{B2} = -1A$$

CPH3123

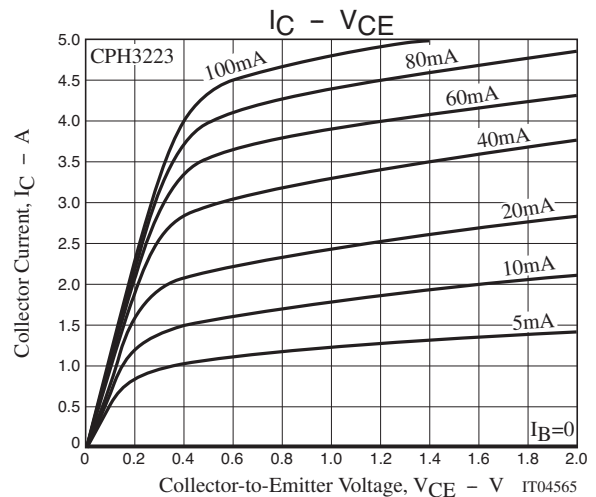
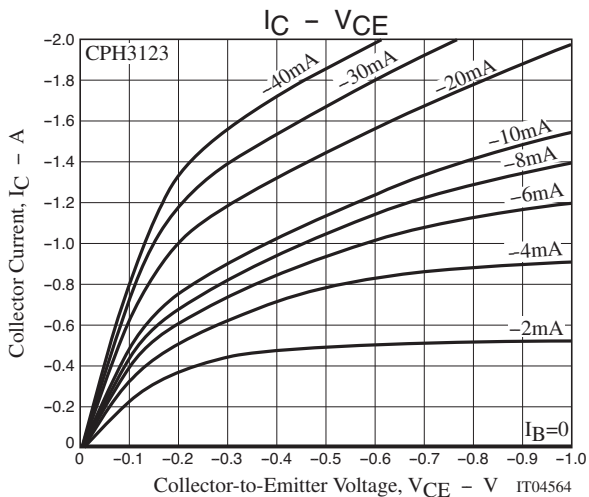


$$I_C = 10I_{B1} = -10I_{B2} = 1A$$

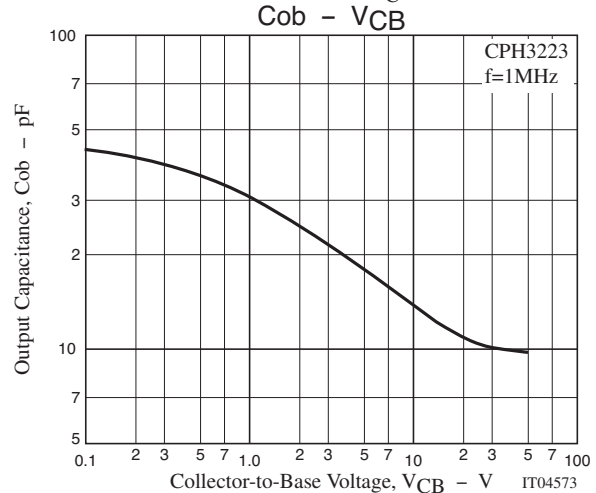
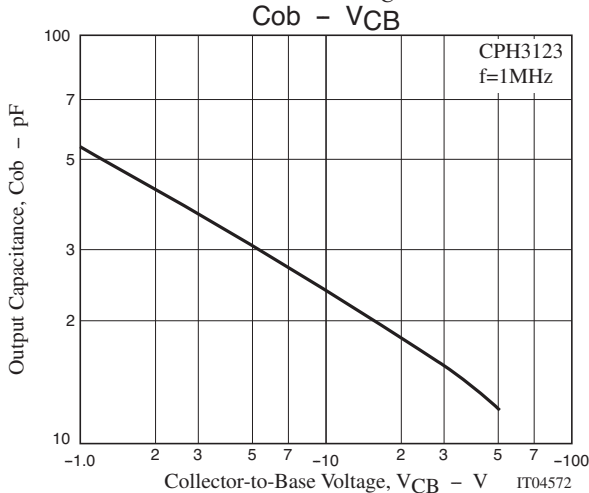
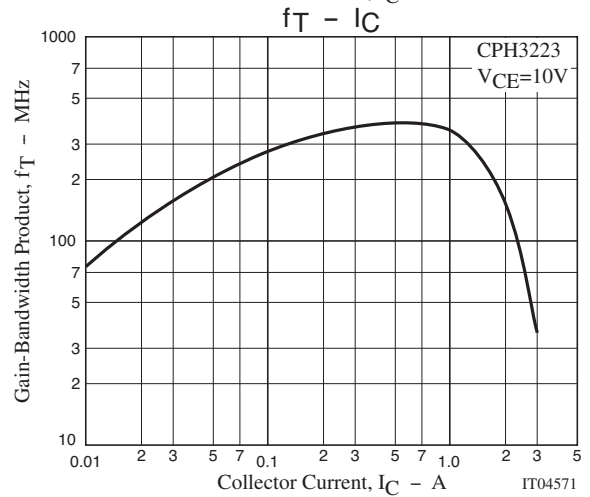
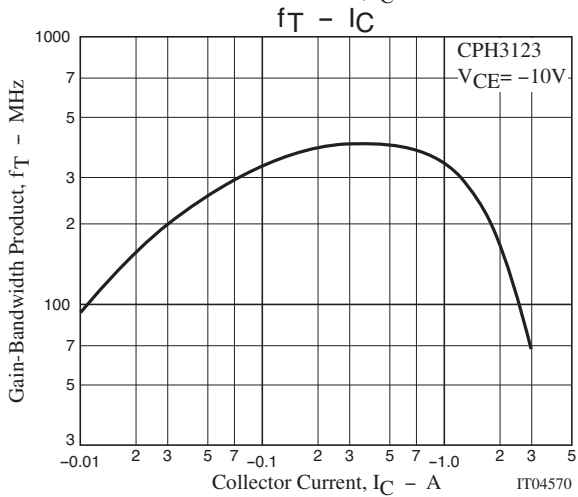
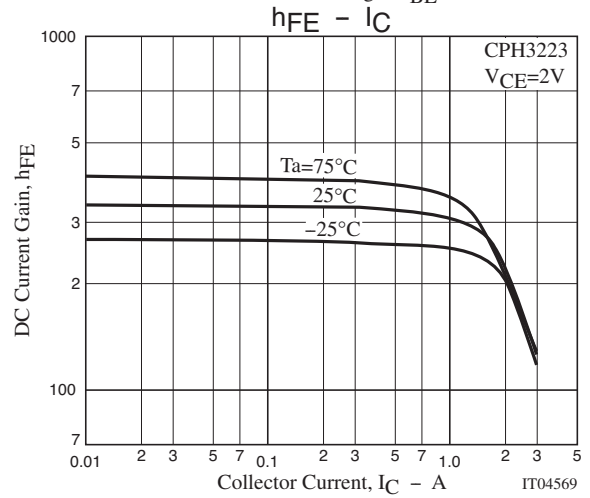
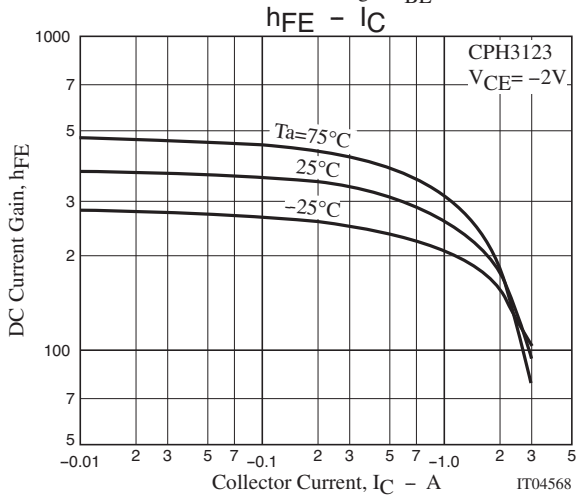
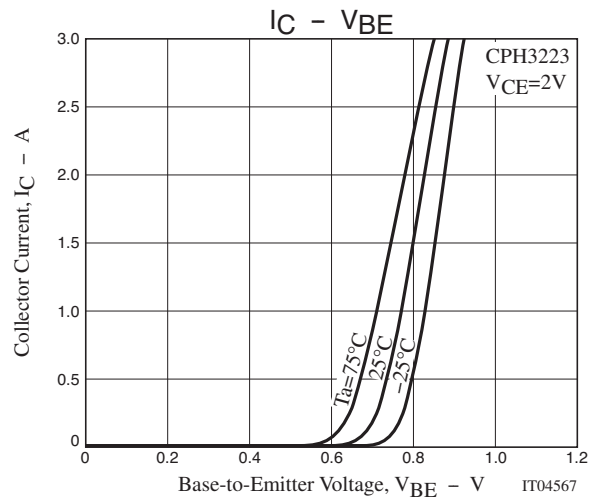
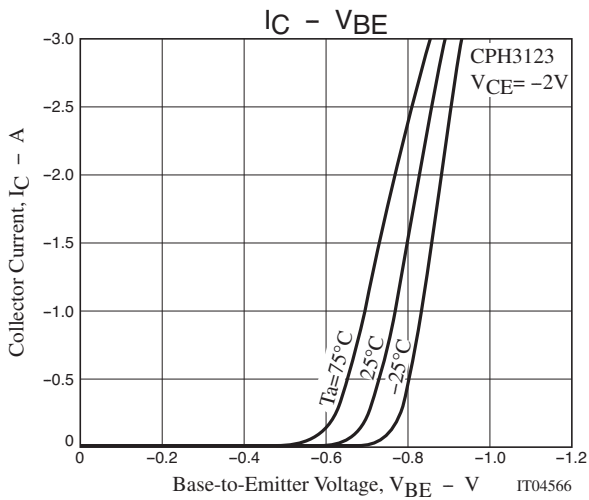
CPH3223

Ordering Information

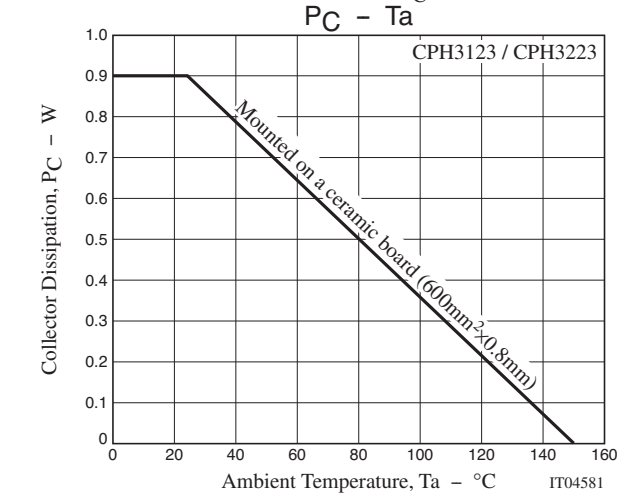
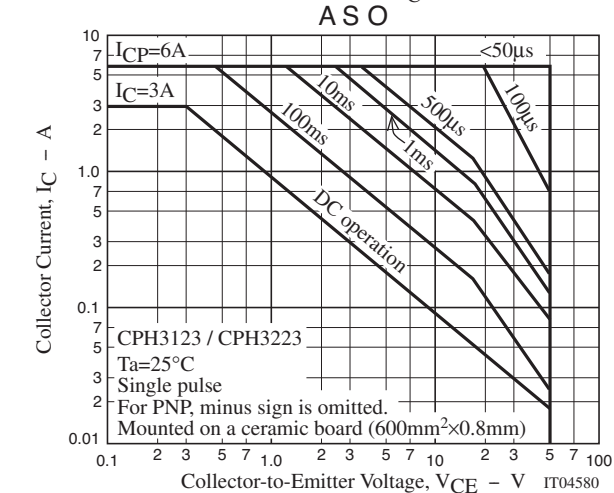
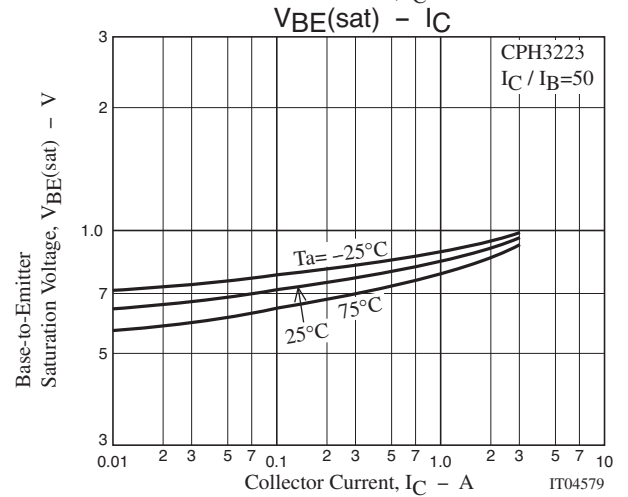
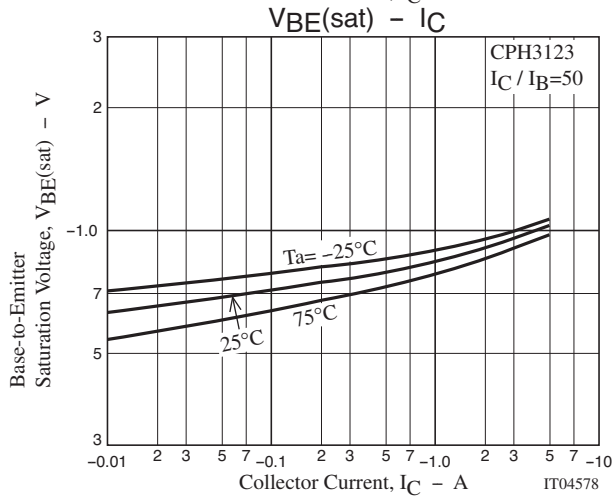
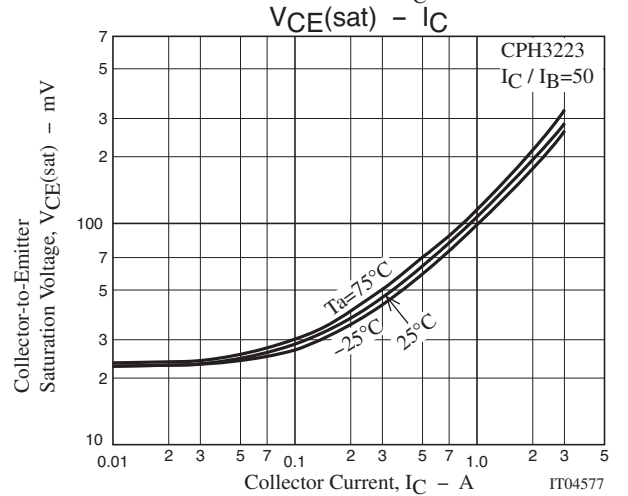
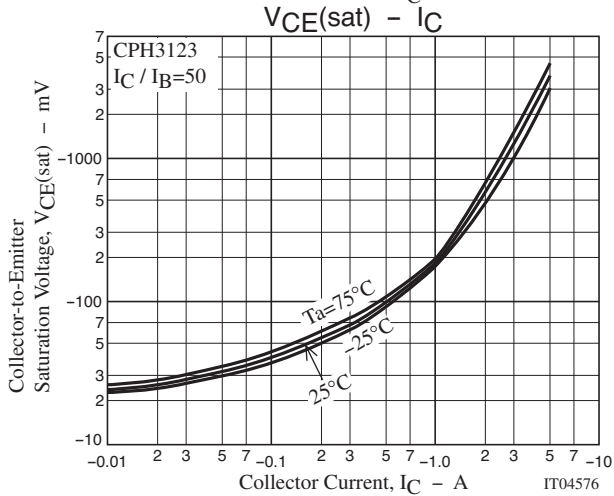
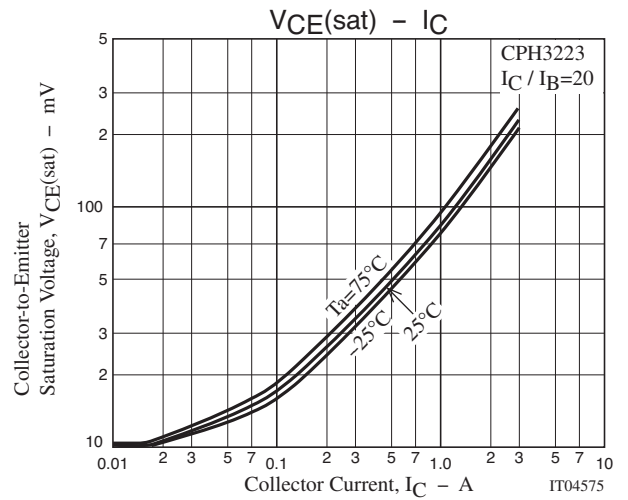
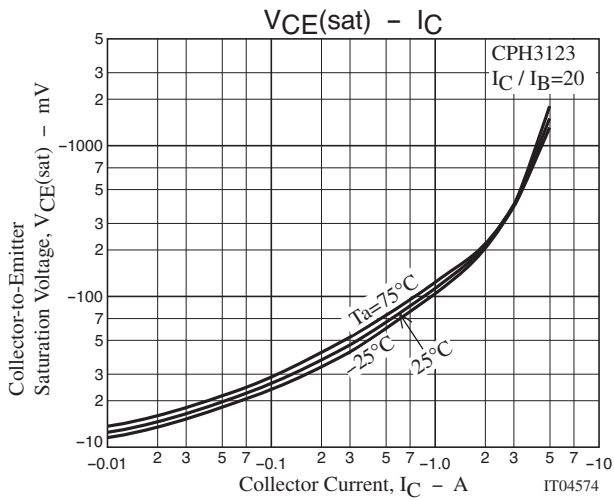
Device	Package	Shipping	memo
CPH3123-TL-E	CPH3	3,000pcs./reel	Pb Free
CPH3223-TL-E	CPH3	3,000pcs./reel	Pb Free



CPH3123/CPH3223



CPH3123/CPH3223



CPH3123/CPH3223

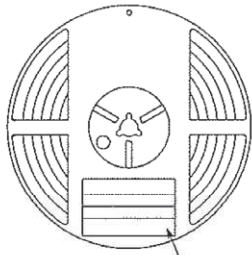
Embossed Taping Specification

CPH3123-TL-E, CPH3223-TL-E

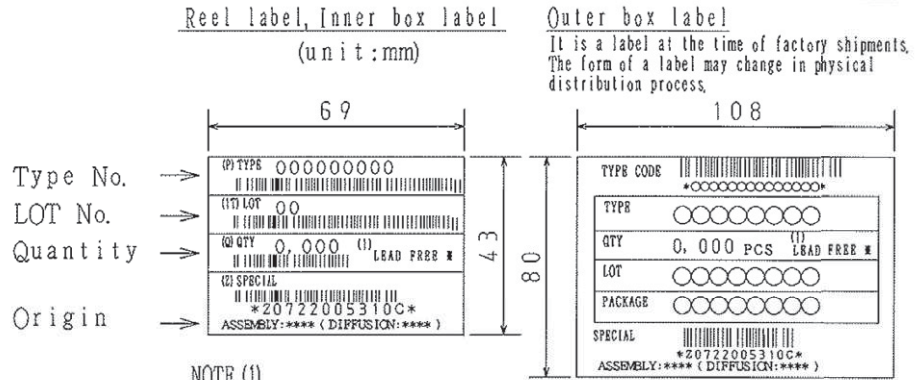
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CPH3	CPH3	3,000	15,000	90,000	5 reels contained Dimensions: mm (external) 183×72×185	6 inner boxes contained Dimensions: mm (external) 440×195×210

Packing method



Reel label



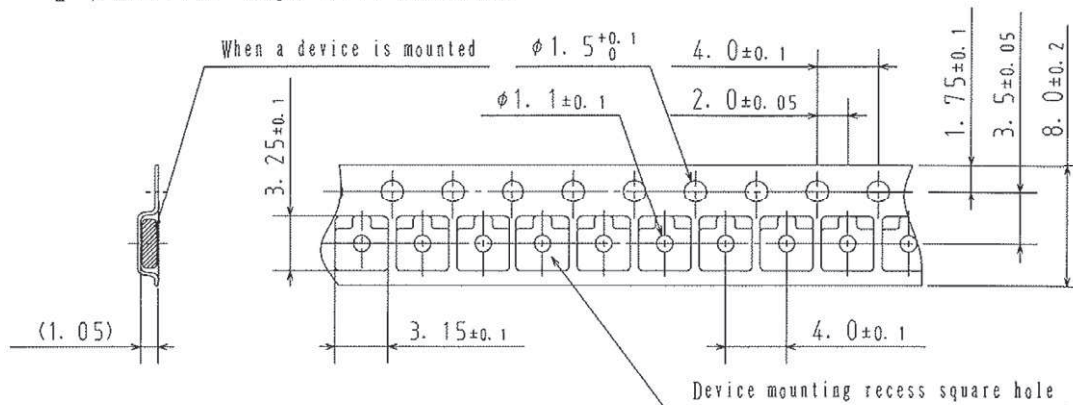
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

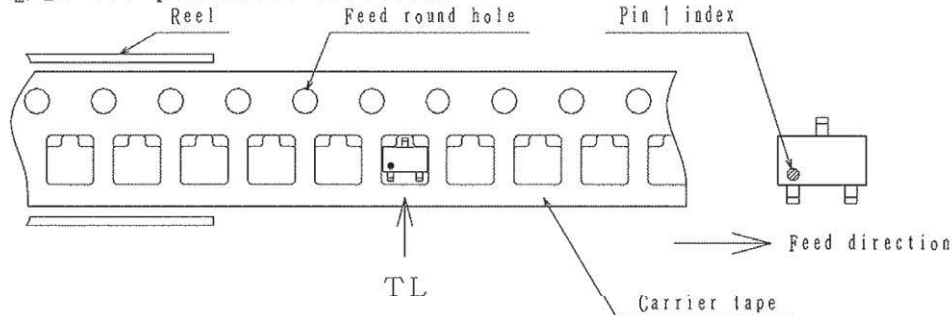
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit: mm)



2-2. Device placement direction

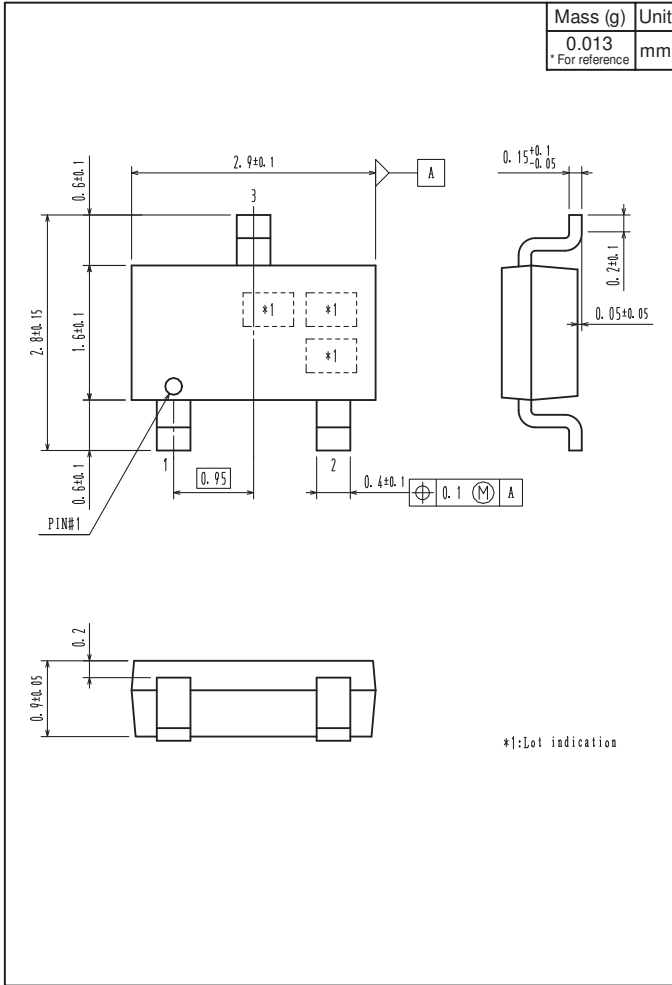


Those with one electrode terminal on the feed hole side.....TL

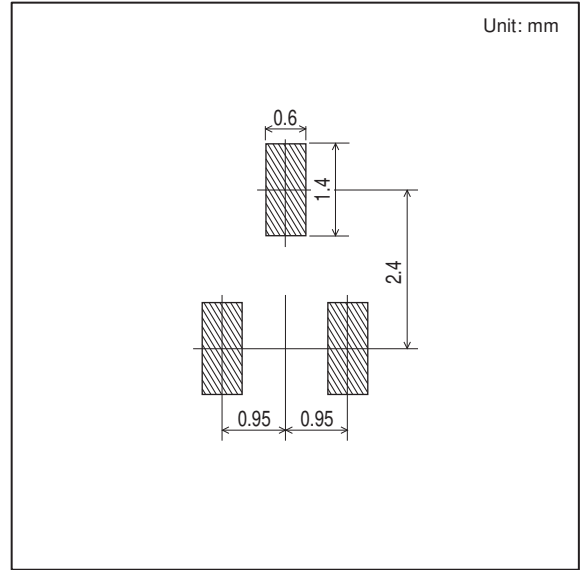
CPH3123/CPH3223

Outline Drawing

CPH3123-TL-E, CPH3223-TL-E



Land Pattern Example



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